



RELIABILITY REPORT
FOR
MAX6612MXK+
PLASTIC ENCAPSULATED DEVICES

January 7, 2009

MAXIM INTEGRATED PRODUCTS

120 SAN GABRIEL DR.
SUNNYVALE, CA 94086

| |
|-----------------------------------|
| Approved by |
| Ken Wendel |
| Quality Assurance |
| Director, Reliability Engineering |

Conclusion

The MAX6612MXK+ successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

Table of Contents

| | |
|-----------------------------------|--------------------------------------|
| I.Device Description | V.Quality Assurance Information |
| II.Manufacturing Information | VI.Reliability Evaluation |
| III.Packaging Information | IV.Die Information |
|Attachments | |

I. Device Description

A. General

The MAX6612 is a low-power precision analog output temperature sensor in a tiny 5-pin SC70 package. The sensitivity of the output voltage to temperature is a high 19.53mV/°C. This sensitivity provides superior noise immunity. The voltage/temperature slope is chosen to provide convenient bit weights when the MAX6612 drives the input of an ADC with a 2.5V or 5V reference. The MAX6612 provides an analog voltage output proportional to temperature. Accuracy is $\pm 1.2^{\circ}\text{C}$ (max) at $+25^{\circ}\text{C}$, $\pm 3.0^{\circ}\text{C}$ (max) from $T_A = 0^{\circ}\text{C}$ to $+70^{\circ}\text{C}$, and $\pm 5.5^{\circ}\text{C}$ (max) from $T_A = -10^{\circ}\text{C}$ to $+125^{\circ}\text{C}$. Useful measurements can be obtained at temperatures as high as $+150^{\circ}\text{C}$. Self-heating effects are negligible due to the low current consumption of the part. Unlike many analog temperature sensors, the MAX6612 is stable with large capacitive loads. Any capacitive load greater than or equal to 1000pF yields stable operation, providing broad flexibility in board-level design. The operating temperature range varies with the supply voltage, with a higher supply voltage enabling a wider temperature range. The MAX6612 can be used over a range of -10°C to $+125^{\circ}\text{C}$ with a supply voltage of 3.3V or greater. For applications with a supply voltage of 2.4V, the MAX6612 can be used over a temperature range of -10°C to $+70^{\circ}\text{C}$.

II. Manufacturing Information

| | |
|----------------------------------|---|
| A. Description/Function: | High-Slope, Low-Power, Analog Temperature Sensor in an SC70 Package |
| B. Process: | B8 |
| C. Number of Device Transistors: | |
| D. Fabrication Location: | Texas |
| E. Assembly Location: | Carsem Malaysia, Hana Thailand, UTL Thailand, Unisem Malaysia |
| F. Date of Initial Production: | July 27, 2002 |

III. Packaging Information

| | |
|--|--------------------------|
| A. Package Type: | 5-pin SC70 |
| B. Lead Frame: | Alloy42 |
| C. Lead Finish: | 100% matte Tin |
| D. Die Attach: | Conductive Epoxy |
| E. Bondwire: | Gold (1 mil dia.) |
| F. Mold Material: | Epoxy with silica filler |
| G. Assembly Diagram: | #05-2901-0044 |
| H. Flammability Rating: | Class UL94-V0 |
| I. Classification of Moisture Sensitivity per JEDEC standard J-STD-020-C | Level 1 |
| J. Single Layer Theta Ja: | 324°C/W |
| K. Single Layer Theta Jc: | 115°C/W |

IV. Die Information

| | |
|----------------------------|---|
| A. Dimensions: | 30 X 31 mils |
| B. Passivation: | Si ₃ N ₄ /SiO ₂ (Silicon nitride/ Silicon dioxide) |
| C. Interconnect: | Aluminum/Si (Si = 1%) |
| D. Backside Metallization: | None |
| E. Minimum Metal Width: | 0.8 microns (as drawn) |
| F. Minimum Metal Spacing: | 0.8 microns (as drawn) |
| G. Bondpad Dimensions: | 5 mil. Sq. |
| H. Isolation Dielectric: | SiO ₂ |
| I. Die Separation Method: | Wafer Saw |

V. Quality Assurance Information

| | |
|-----------------------------------|---|
| A. Quality Assurance Contacts: | Ken Wendel (Director, Reliability Engineering) Bryan Preeshl (Managing Director of QA) |
| B. Outgoing Inspection Level: | 0.1% for all electrical parameters guaranteed by the Datasheet. 0.1% For all Visual Defects. |
| C. Observed Outgoing Defect Rate: | < 50 ppm |
| D. Sampling Plan: | Mil-Std-105D |

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in Table 1. Using these results, the Failure Rate (λ) is calculated as follows:

$$\lambda = \frac{1}{\text{MTTF}} = \frac{1.83}{192 \times 4340 \times 79 \times 2} \quad (\text{Chi square value for MTTF upper limit})$$

(where 4340 = Temperature Acceleration factor assuming an activation energy of 0.8eV)

$$\lambda = 13.6 \times 10^{-9}$$

$$\lambda = 13.6 \text{ F.I.T. (60\% confidence level @ 25°C)}$$

The following failure rate represents data collected from Maxim's reliability monitor program. Maxim performs quarterly 1000 hour life test monitors on its processes. This data is published in the Product Reliability Report found at <http://www.maxim-ic.com/>. Current monitor data for the B8 Process results in a FIT Rate of 2.71 @ 25C and 17.30 @ 55C (0.8 eV, 60% UCL)

B. Moisture Resistance Tests

The industry standard 85°C/85%RH or HAST testing is monitored per device process once a quarter.

C. E.S.D. and Latch-Up Testing

The TS43 die type has been found to have all pins able to withstand a HBM transient pulse of +/-500 V per JEDEC JESD22-A114-D. Latch-Up testing has shown that this device withstands a current of +/-250 mA.

Table 1
Reliability Evaluation Test Results

MAX6612MXK+

| TEST ITEM | TEST CONDITION | FAILURE IDENTIFICATION | SAMPLE SIZE | NUMBER OF FAILURES |
|---|--|----------------------------------|-------------|--------------------|
| Static Life Test (Note 1) | Ta = 135°C Biased Time = 192 hrs. | DC Parameters & functionality | 79 | 0 |
| Moisture Testing (Note 2) 85/85 | Ta = 85°C RH = 85% Biased Time = 1000hrs. | DC Parameters & functionality | 77 | 0 |
| Mechanical Stress (Note 2) Temperature Cycle | -65°C/150°C 1000 Cycles Method 1010 | DC Parameters & functionality | 77 | 0 |

Note 1: Life Test Data may represent plastic DIP qualification lots.

Note 2: Generic Package/Process data